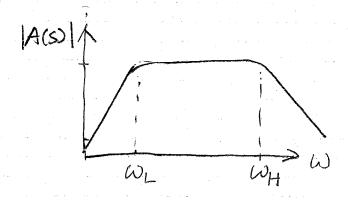
High Frequency Response of CE Amplifiers

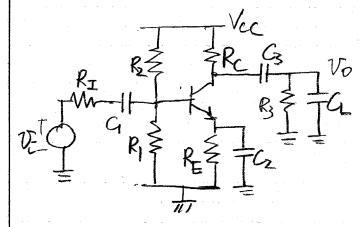


A(S)=A<sub>mīd</sub> F<sub>2</sub>(S) F<sub>H</sub>(S)
The low frequency response F<sub>2</sub>(S) is primarily determined by the bypass and coupling capacitors.

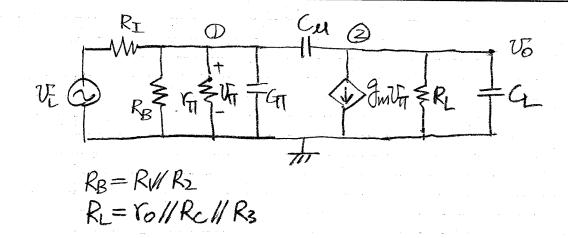
The high frequency response FH(s) is primarily determined by the intrinsic capacitances of the transistors, such as {G, Cu in BJT (typically in UF)

(Cos, Cas in BJT (typically in UT)
(Cos, Cas in MOS (typically < NF)

Common-Emitter (CE) amplifier



High-frequency equivalent clet ① Replace C1, C2, C3 by short clet ② Use high-frequency hybrid-pi model for BJT



$$\Rightarrow \overline{V_0}\left(\frac{1}{R} + S(Cu+Cu)\right) = \frac{-\left(\frac{2}{3}m-Cu\right)\left(S(u\cdot V_0 + \frac{V_c}{RL})\right)}{\frac{1}{R}i + S(Cu+Cu)}$$

$$\Rightarrow A(S) = \frac{V_0}{V_{\overline{c}}} = -g_{m}R_{L}\frac{R'}{R_{\overline{L}}} \frac{(1 - S \frac{Cu}{g_{m}})}{f(S)}$$

$$f(s) = 1 + s \left[ R'(G_0 + C_0 + f_m R_L C_0) + R_L(C_0 + C_L) \right]$$

$$+ s^2 \left[ R_L R'(C_0 G_0 + G_L G_0) \right]$$

$$\overline{F_{H}(S)} = \frac{1 + \frac{S}{\omega_{Z}}}{(1 + \frac{S}{\omega_{P}})(1 + \frac{S}{\omega_{P}})}$$

RHP zero 
$$\approx \omega_z = \frac{g_m}{Cu} > \omega_T = \frac{g_m}{CutGa}$$

much higher than WH (": GT >> Car)

Assume there is a dominant pole.

$$D(S) = (1 + \frac{S}{\omega_{Pl}})(1 + \frac{S^2}{\omega_{Pl}})$$
$$= 1 + S(\frac{1}{\omega_{Pl}} + \frac{1}{\omega_{Pl}}) + \frac{S^2}{\omega_{Pl}\omega_{Pl}}$$

$$D(S) \approx 1 + \frac{S}{\omega p_1} + \frac{S^2}{\omega p_1 \omega p_2} = 1 + A_1 S + A_2 S^2$$

WP2 = 
$$\frac{1}{A_2/A_1} = \frac{A_1}{A_2} = \frac{R'(G_T + (L+S_mR_L)Cu + R_L(Cu+CL))}{R_LR'(CuG_T + C_LG_T + C_LCu)}$$

Need to verify wp. >> wp.

If we assume Go > Cu, CL

The dominant pole way

Sum of RC times,

Open-Circuit Time Constant (OCTC) Method Approximation to quickly find dominant pole In high frequency response

$$F_{H(S)} = \frac{(1+\frac{S}{\omega z_{1}})(1+\frac{S}{\omega z_{2}})(---)}{(1+\frac{S}{\omega p_{1}})(1+\frac{S}{\omega p_{2}})(---)} = \frac{1+\alpha_{1}S+\alpha_{2}S^{2}+\cdots}{1+b_{1}S+b_{2}S^{2}+\cdots}$$

Through network theory, one can prove

G= capacitors in H.F. circuit

Ro: resistances measured at terminals of G, with other capacitors open-circuited.

and all independent voltage sources short-circuited, all independent current sources open-circuited.

Now use dominant pole approximation:

$$b_1 \approx \frac{1}{\omega_H}$$

$$\omega_H = \frac{1}{\omega_H} = \frac{1}{\sum_{i} R_{ij} G_i}$$

OCTC analysis of CE amplifier

$$V_{T}$$
 $V_{T}$ 
 $V_{T}$ 

Reso = RL+R'(1+gmRL)

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Same as brute force solution! But much easier to analyze. 
$$C = \frac{\Delta Q}{\Delta V}$$
  
 $\Delta Q = G_{Y}(\Delta V_{x} - \Delta V_{y}) = G_{Y}(1 - A_{XY}) \cdot \Delta V_{X}$   
Can be considered as an equivalent capacitance on the input side:

The content side  $\triangle Q = (1 - \frac{1}{4}x^{2}) + \frac{1}{4}x^{2} + \frac{1}{$ 

OCTC

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